



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



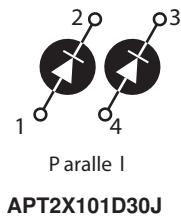
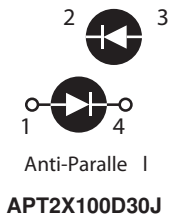
## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





APT2X101D30J 300V 100A  
APT2X100D30J 300V 100A

## DUAL DIE ISOTOP® PACKAGE

### ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
<ul style="list-style-type: none"> <li>• Anti-Parallel Diode               <ul style="list-style-type: none"> <li>-Switchmode Power Supply</li> <li>-Inverters</li> </ul> </li> <li>• Free Wheeling Diode               <ul style="list-style-type: none"> <li>-Motor Controllers</li> <li>-Converters</li> </ul> </li> <li>• Snubber Diode</li> <li>• Uninterruptible Power Supply (UPS)</li> <li>• Induction Heating</li> <li>• High Speed Rectifiers</li> </ul>	<ul style="list-style-type: none"> <li>• Ultrafast Recovery Times</li> <li>• Soft Recovery Characteristics</li> <li>• Popular SOT-227 Package</li> <li>• Low Forward Voltage</li> <li>• High Blocking Voltage</li> <li>• Low Leakage Current</li> </ul>	<ul style="list-style-type: none"> <li>• Low Losses</li> <li>• Low Noise Switching</li> <li>• Cooler Operation</li> <li>• Higher Reliability Systems</li> <li>• Increased System Power Density</li> </ul>

#### MAXIMUM RATINGS

All Ratings:  $T_C = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT2X100_101D30J	UNIT
$V_R$	Maximum D.C. Reverse Voltage	300	Volts
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		
$V_{RWM}$	Maximum Working Peak Reverse Voltage		
$I_F(AV)$	Maximum Average Forward Current ( $T_C = 115^\circ\text{C}$ , Duty Cycle = 0.5)	100	Amps
$I_F(RMS)$	RMS Forward Current (Square wave, 50% duty)	183	
$I_{FSM}$	Non-Repetitive Forward Surge Current ( $T_J = 45^\circ\text{C}$ , 8.3ms)	1000	
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$T_L$	Lead Temperature for 10 Sec.	300	

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol		MIN	TYP	MAX	UNIT	
$V_F$	Forward Voltage		$I_F = 100\text{A}$	1.2	1.4	Volts
			$I_F = 200\text{A}$	1.5		
			$I_F = 100\text{A}, T_J = 125^\circ\text{C}$	1.0		
$I_{RM}$	Maximum Reverse Leakage Current		$V_R = V_R$ Rated		500	$\mu\text{A}$
			$V_R = V_R$ Rated, $T_J = 125^\circ\text{C}$		1000	
$C_T$	Junction Capacitance, $V_R = 200\text{V}$		270		pF	

**DYNAMIC CHARACTERISTICS**

APT2X100\_101D30J

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
$t_{rr}$	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^\circ C$	-	36		ns
$t_{rr}$	Reverse Recovery Time		-	47		
$Q_{rr}$	Reverse Recovery Charge			-	120	
$I_{RRM}$	Maximum Reverse Recovery Current	$I_F = 100A, di_F/dt = -200A/\mu s, V_R = 200V, T_C = 25^\circ C$	-	5	-	Amps
$t_{rr}$	Reverse Recovery Time		-	110		ns
$Q_{rr}$	Reverse Recovery Charge		-	650		nC
$I_{RRM}$	Maximum Reverse Recovery Current	$I_F = 100A, di_F/dt = -200A/\mu s, V_R = 200V, T_C = 125^\circ C$	-	10	-	Amps
$t_{rr}$	Reverse Recovery Time		-	70		ns
$Q_{rr}$	Reverse Recovery Charge		-	1490		nC
$I_{RRM}$	Maximum Reverse Recovery Current	$I_F = 100A, di_F/dt = -1000A/\mu s, V_R = 200V, T_C = 125^\circ C$	-	37		Amps

**THERMAL AND MECHANICAL CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.42	$^\circ C/W$
$V_{isolation}$	RMS Voltage			20	
$W_T$	Package Weight		1.03		oz
			29.2		g
Torque	Maximum Terminal & Mounting Torque			10	lb•in
				1.1	N•m

Microsemi Reserves the right to change, without notice, the specifications and information contained herein.

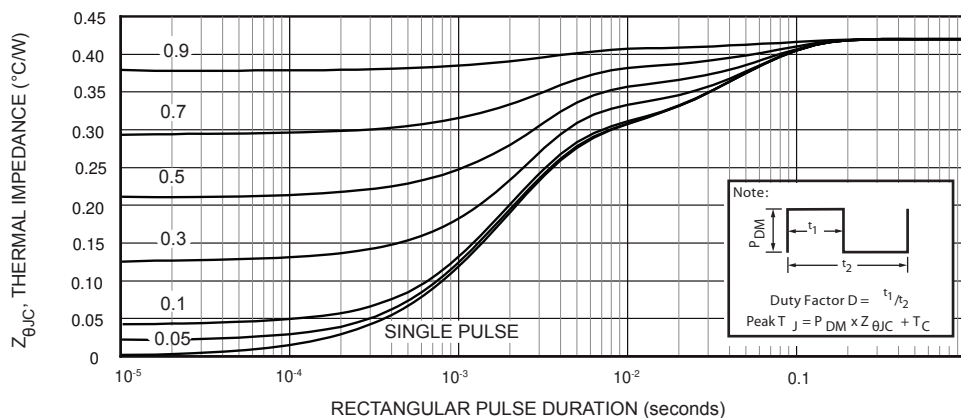


FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION



# TYPICAL PERFORMANCE CURVES

APT2X100\_101D30J

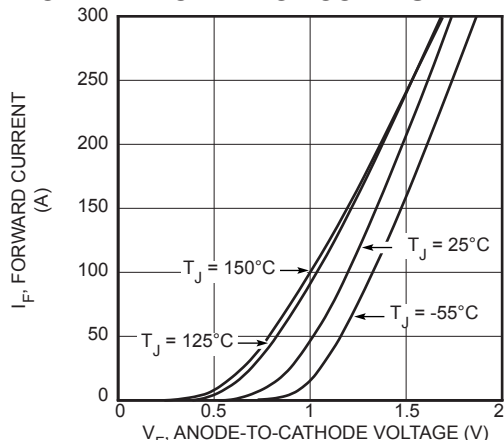


Figure 2. Forward Current vs. Forward Voltage

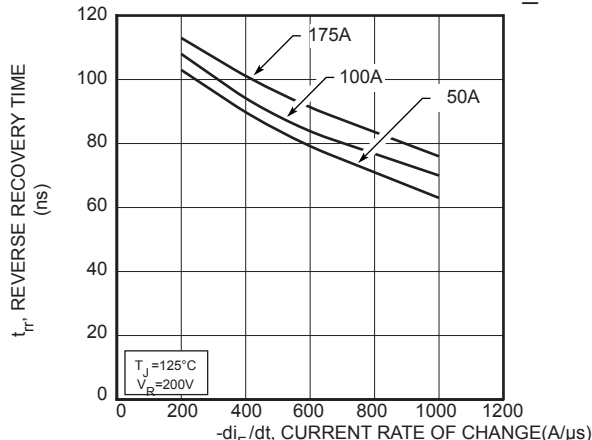


Figure 3. Reverse Recovery Time vs. Current Rate of Change

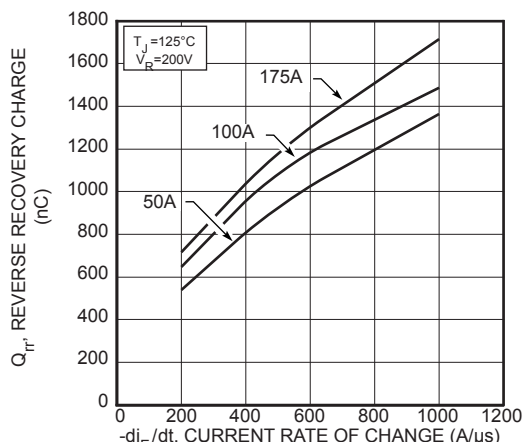


Figure 4. Reverse Recovery Charge vs. Current Rate of Change

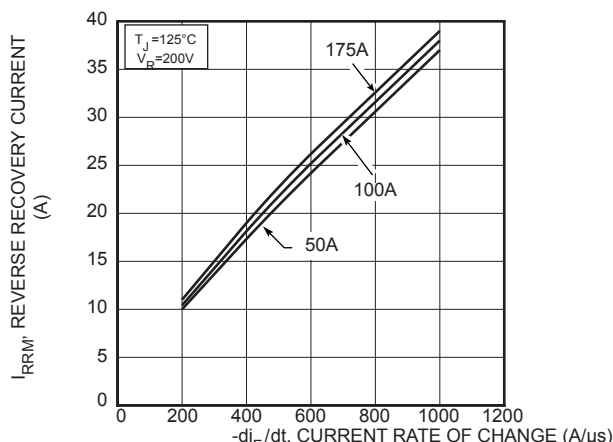


Figure 5. Reverse Recovery Current vs. Current Rate of Change

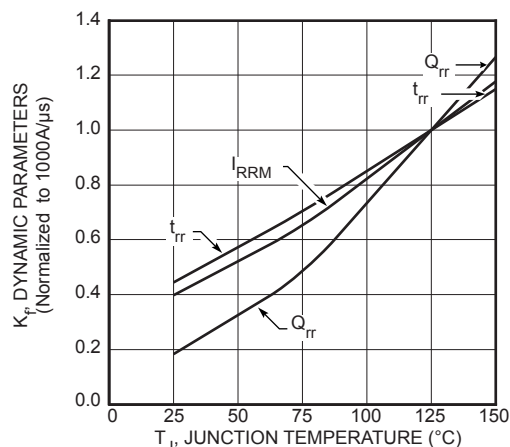


Figure 6. Dynamic Parameters vs. Junction Temperature

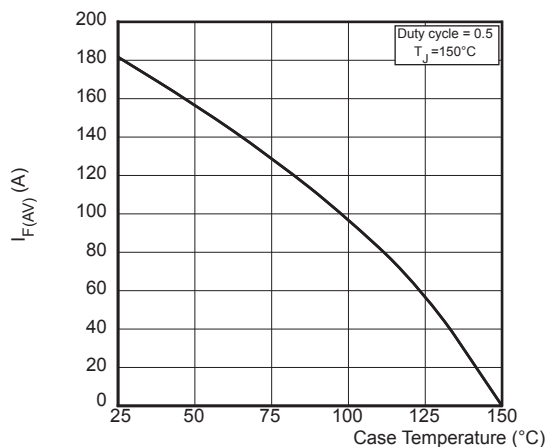


Figure 7. Maximum Average Forward Current vs. Case Temperature

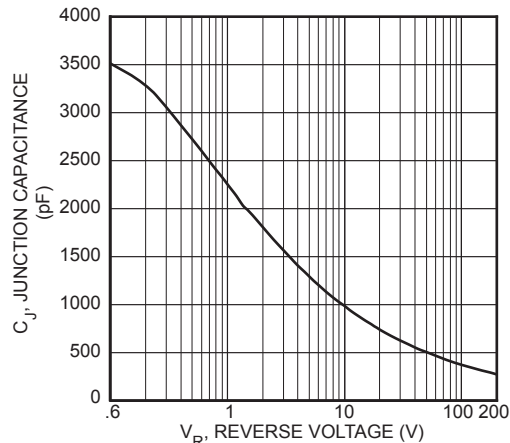


Figure 8. Junction Capacitance vs. Reverse Voltage

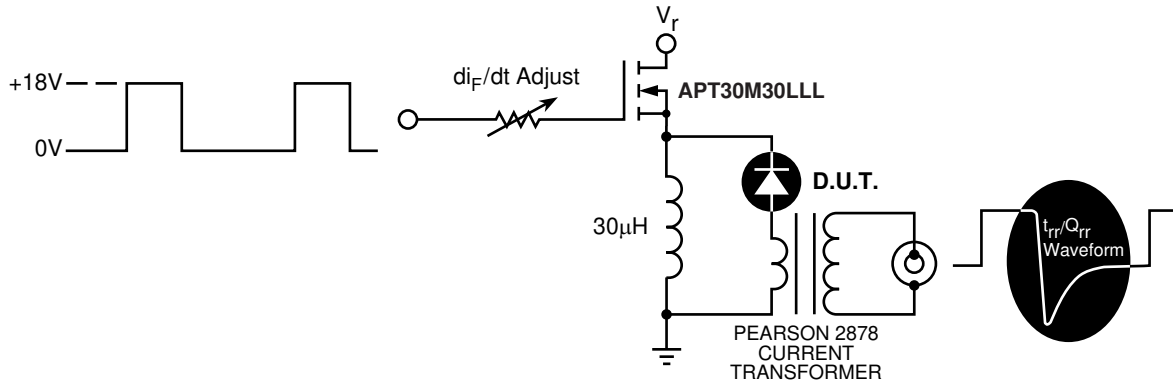


Figure 9. Diode Test Circuit

- 1  $I_F$  - Forward Conduction Current
- 2  $di_F/dt$  - Rate of Diode Current Change Through Zero Crossing.
- 3  $I_{RRM}$  - Maximum Reverse Recovery Current.
- 4  $t_{rr}$  - Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through  $I_{RRM}$  and  $0.25 \cdot I_{RRM}$  passes through zero.
- 5  $Q_{rr}$  - Area Under the Curve Defined by  $I_{RRM}$  and  $t_{rr}$ .

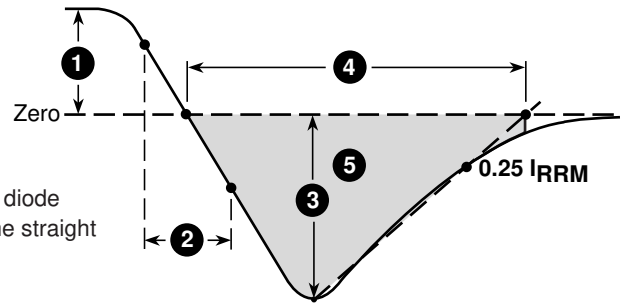


Figure 10, Diode Reverse Recovery Waveform and Definitions

SOT-227 Package Outline

